### Resonator

# Piezoelectric Resonator

# FAR Family (C1, C3, C4 series)

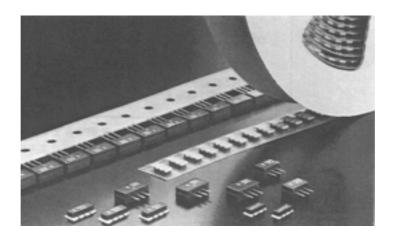
#### **■ DESCRIPTION**

Fujitsu resonators (C1, C3, C4 series) feature originally developed single crystals with a high electromechanical coupling coefficient (LiTaO3: lithium tantalate, LiNbO3: lithium niobate), the result is compact packaging. Three series are available: the C3 and C4 series with built-in capacitors for high integration, for exclusive use in microcomputer clocks; and the C1 series for high precision. All series include the CHIP type device for surfacemount and the SIP type device for general PC boards.

#### **■ FEATURES**

- Surface-mount technology can be applied to the CHIP type to increase packaging density. The SIP type is only half the height of conventional quartz crystal resonators, and can be easily mounted on general PC boards.
- The C3 and C4 series have been developed for exclusive use in microcomputer clocks. They have built-in capacitors, and the number of components has been reduced to one-third of that of conventional circuits.
- Both the SIP and CHIP types can be shipped in taped packages for automatic mounting.
- The resonators have superior shock and vibration resistance, preventing damage during automatic insertion process.

#### **■ PACKAGE**



### **■ STANDARD CHARACTERISTICS**

Series Parameter	C1 series	C3 series	C4 series
Material	Lithium Tantalate (LiTaO <sub>3</sub> )		Lithium Niobate (LiNbO <sub>3</sub> )
Frequency	3.58 to 10	6 MHz	3 to 16 MHz
Standard frequency	S	ee "■ Standard frequency."	
Initial frequency tolerance	±0.05% (G) ±0.1% (J) ±0.3% (K) ±0.5% (M)	±0.1% (J)	
Temperature characteristics (–20 to 60°C)	±0.02%	±0.05%	±0.5%
Capacity of built-in capacitor	_	20±8 pF	(standard)*
Aging stability	Within ±0.1%		
Operating temperature	−30 to 85°C		
Storage temperature		–40 to 100°C	
Standard measuring circuit	(Resonant frequency and serial resonant resistance)  R: Resonator  75 Ω  OSC  M  M  M  M  M  M  M  M  M  M  M  M  M	(Oscillation frequency)  1 MΩ  C1 C2  FAR	3 MHz to 10 MHz max. IC; 1/6MB84069B x 2 10 MHz to 16 MHz IC; MC74HC04 Vcc; 5 VDC R; Resonator C1, C2: Loading capacitors (built-in)
		<del>┌┈</del> ┆╅╢ <del>┋</del> ┆╅	esonator σ Ω LM

<sup>\*:</sup> The capacity of the built-in capacitor is 20±8 pF by standard.

10±4 pF and 30±8 pF types are also available. However, the characteristics of 10±4 pF and 30±8 pF types are specified by Fujitsu, considering matching data with applied IC (mainly microcomputer).

#### **■ STANDARD FREQUENCY**

Standard	C1/C	3 series	C4 series	
frequency (kHz)	Package size	Resonant resistance	Package size	Resonant resistance
3,580 4,000 4,194 4,915	A A A	300 Ω max. (00)	A A A	150 Ω max. (01)
6,000 6,144 7,373 8,000 10,000 11,000 11,059 12,000 14,746 16.000	8888888888	150 Ω max. (01)	ввввввввв	75 Ω max. (02)

#### · Package sizes and resonant resistance

There are two package sizes according to frequency:

Frequency	Package size
3 to 5.99 MHz	A
6 to 16 MHz	В

For resonant resistance, standard values are specified according to frequency:

F	Standard resonant resistance		
Frequency	C1/C3 series	C4 series	
3 to 3.57 MHz	_	300 Ω max. (00)	
3.58 to 5.99 MHz	300 Ω max. (00)	150 Ω max. (01)	
6 to 16 MHz	150 Ω max. (01)	75 Ω max. (02)	

**Note:** For resonant resistance other than the standard values, they are specified by Fujitsu considering matching data with applied IC (mainly micro computer).

### **■ NOTES ON USE**

- · Handle carefully.
- Solder under the following conditions.

CHIP type: 5 seconds max. at 230°C (PCB)

SIP type: 10 seconds max. at 260°C

Do not apply extreme heat to the resonator. Recommended preheating for the CHIP type is 150°C for one minute.

- Avoid extreme fluctuations in temperature during use.
- There is no specific direction in resonator mounting.
- Additional information is available separately, if required, for designing microcomputer oscillation circuits.
- CHIP type is for reflow solder, not for flow solder.

### **■ PART NUMBERING SYSTEM**



### (1) Series

Series	Single crystal	Capacitor
C1	LiTaO₃	_
C3	LiTaO₃	With built-in capacitors
C4	LiNbO <sub>3</sub>	With built-in capacitors

### (2) Package type

Specification	Туре
С	CHIP
S	SIP

### (3) Package size See Table 1 in "■ Dimensions."

Specification	Size
Α	Large
В	Small

### (4) Frequency (kHz)

Frequency	Designation	Frequency	Designation	Frequency	Designation	Frequency	Designation
3,580 kHz	03580	6,000 kHz	06000	10,000 kHz	10000	14,746 kHz	14746
4,000 kHz	04000	6,144 kHz	06144	11,000 kHz	11000	16,000 kHz	16000
4,194 kHz	04194	7,373 kHz	07373	11,059 kHz	11059		
4,195 kHz	04915	8,000 kHz	08000	12,000 kHz	12000		

## (5) Initial tolerance of frequency See "■ Standard Frequency."

Specification	Tolerance	C1 series	C3 series	C4 series
G	±0.05%	available	_	_
J	±0.1%	available	available	_
К	±0.3%	available	available	available
М	±0.5%	avaialble	available	available
L	±1%	_	_	available

### (6) Capacity of built-in capacitor

Specification	Capacitance
0	20±8 pF
1	10±4 pF
2	30±8 pF

**Note:** For C1 series, only "0" is available.

### (7) Resonant resistance

Specification	Resonant resistance
0	300 Ω max.
1	150 Ω max.
2	75 Ω max.

### (8) User-specific Special Symbols

Specification	Description	
Name	No specification, no taping specification	
_	No specification, with taping specification	
A to Z	Serial number for custom design	

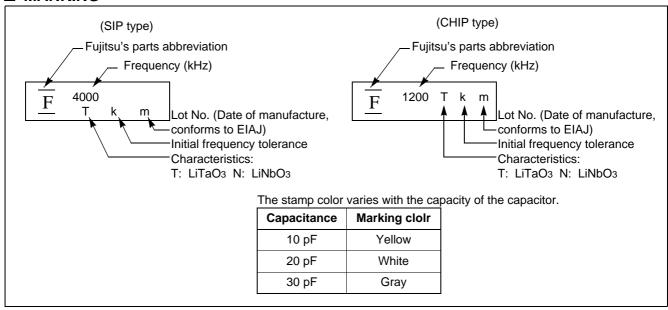
## (9)Taping specificationSIP type

Specification	Description
<b>–</b> Т	Reel pack
_U	Ammo pack

### • CHIP type

Specification	Description
–R	16 mm carrier pack

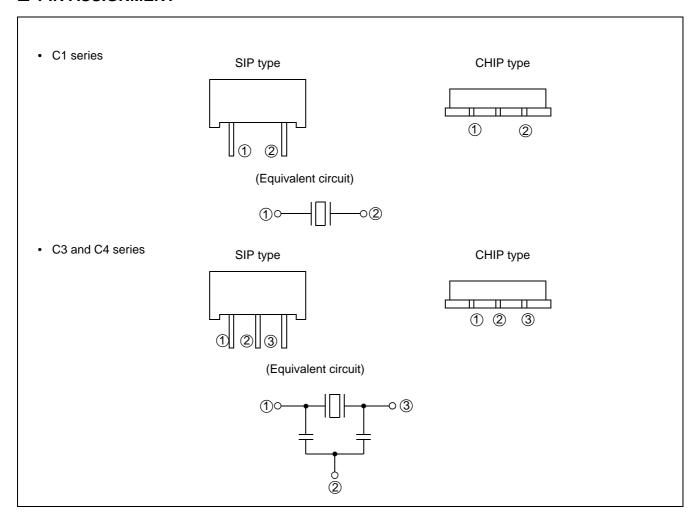
### **■ MARKING**



Data code (EIAJ standard) is specified as follows in a four-year cycle.

Year	Month	Symbol	Year	Month	Symbol	Year	Month	Symbol	Year	Month	Symbol
	1	А	1978	1	N	1979	1	а	1980	1	n
	2	В		2	Р		2	b		2	P
	3	С		3	Q		3	<del>c</del>		3	q
1977	4	D		4	R		4	d		4	r
1981	5	Е	1982	5	Е	1983	5	е	1984	5	1
1985	6	F	1986	6	Т	1987	6	f	1988	6	t
1989	7	G	1990 1994	7	U	1991 1995	7	9	1992	7	u
	8	Н		8	V		8	h		8	U
1993	9	J		9	W		9	j		9	w
	10	K		10	X		10	k		10	x
	11	L		11	Y		11	Q		11	¥
	12	М		12	Z		12	т		12	3

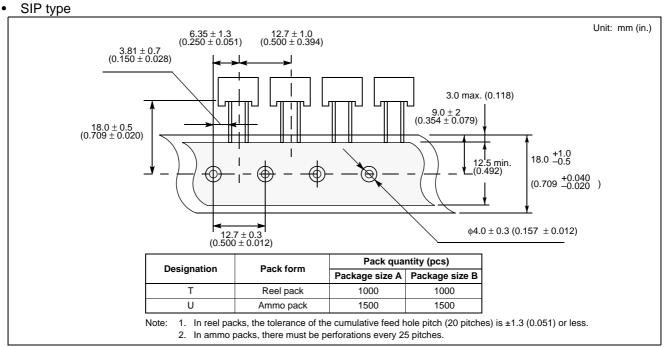
### **■ PIN ASSIGNMENT**



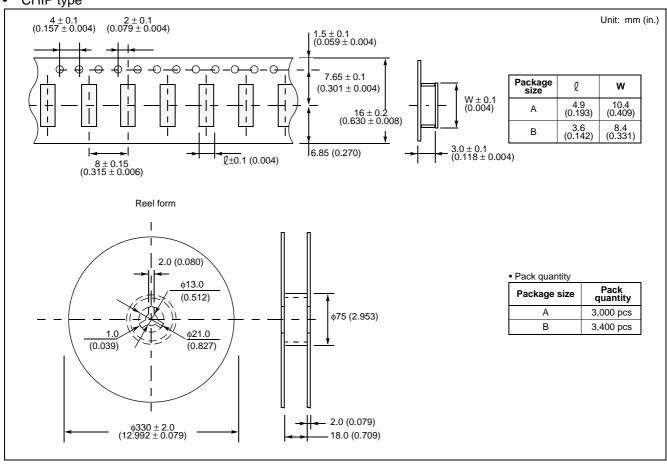
#### **■ DIMENSIONS**

#### Table 1 Package size Unit: mm (in.) L W Н Type L<sub>1</sub> Three terminal Two terminal 4.3 ± 0.2 (0.169 ± 0.008) $11.0 \pm 0.2$ (0.433 ± 0.008) $6.3 \pm 0.2$ $(0.248 \pm 0.008)$ Α SIP type $9.0 \pm 0.2$ (0.354 ± 0.008) $4.3 \pm 0.2$ (0.169 ± 0.008) $5.3 \pm 0.2$ (0.209 ± 0.008) $5.08 \pm 0.2$ (0.200 ± 0.008) $2.54 \pm 0.2$ (0.100 ± 0.008) 10.0 ± 0.5 (0.394 ± 0.020) $2.5 \pm 0.3$ (0.098 ± 0.012) $9.4 \pm 0.2$ (0.370 ± 0.008) $4.5 \pm 0.5$ (0.177 ± 0.020) Α CHIP type $7.4 \pm 0.2$ (0.291 ± 0.008) $3.2 \pm 0.5$ $(0.126 \pm 0.020)$ $2.5 \pm 0.3$ (0.098 ± 0.012) $8.0 \pm 0.5$ $(0.315 \pm 0.020)$ SIP type 0.35 ± 0.1 (0.014 ± 0.004) 0.35 ± 0.1 (0.014 ± 0.004) $0.5 \pm \overline{0.2}$ (0.020 ± 0.008) $0.5 \pm 0.2$ (0.020 $\pm$ 0.008) 3.4 ± 0.2 (0.134 ± 0.008) $3.4 \pm 0.2 \\ (0.134 \pm 0.008)$ C1 series C3 and C4 series CHIP type Н Н 1.5 (0.059)(0.059)(0.059)W W 0.45 (0.018)(0.037)(0.018)(0.037)C1 series C3 series C4 series

#### **■ TAPING FORM AND DIMENSIONS**

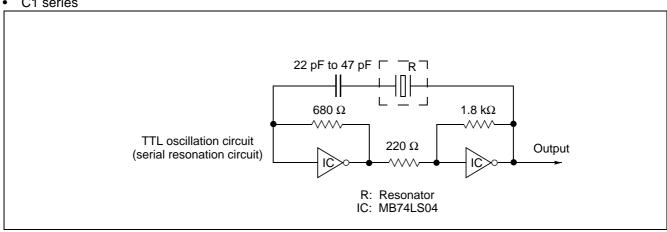




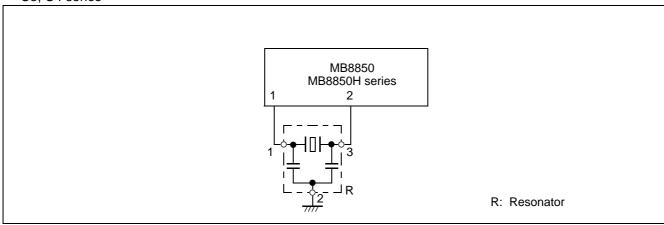


### **■ APPLICATION EXAMPLES**

### C1 series



### C3, C4 series



### **■ RELIABILITY**

Parameter	Test conditions	Requirements
Shock	MIL-STD-883B, 2002, condtion C (3000G)	Frequency fluctuation: within ±0.1%
Vibration	MIL-STD-202E, 201A (1.5 mm <0.059> at 10 Hz to 55 Hz for 2 hours)	Frequency fluctuation: within ±0.1%
Drop	5 times drop from 1 m (39.370 in.) height to wooden board.	Frequency fluctuation: within ±0.1%
Sealing	Immersion in water at 85°C	No bubbles observed
Heat resistance	MIL-STD-202E, 210A condition B (260°C • 5 sec.)	Frequency fluctuation: within ±0.1%
Temperature cycling	MIL-STD-883B, 1010, condition A (–35 to 85°C, 10 cycle)	Frequency fluctuation: within ±0.1%
High-temperature loading test	MIL-STD-883B, 1008, condition B 1000 h (100°C • 1000 hours)	Frequency fluctuation: within ±0.1%
High-temperature humidity test	MIL-STD-202E, 103A, condition B (96 hours at 60°C, 90% to 95% RH, 12 VDC)	Frequency fluctuation: within ±0.1%

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